NSN 5961-01-376-4275



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-376-4275 **Inclosure Material:** Plastic **Overall Length:** Between 1.334 inches and 1.383 inches **Overall Height:** Between 0.185 inches and 0.209 inches **Overall Width:** Between 0.602 inches and 0.626 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-247ac **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 42.00 amperes drain current **Power Rating Per Characteristic:** 160.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 3 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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